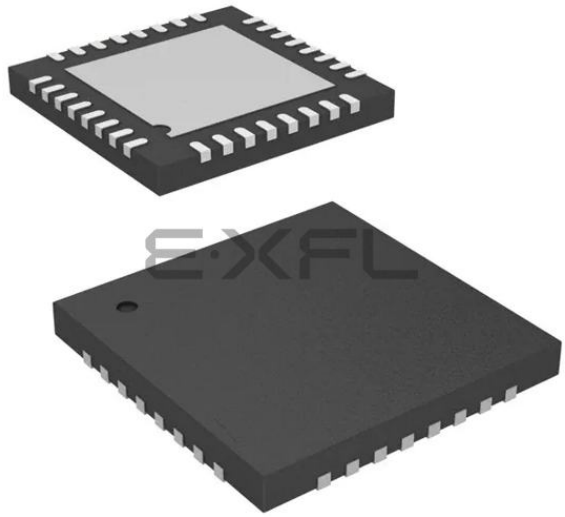

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What Are Embedded - Microcontrollers - Application Specific?

Application-specific microcontrollers are engineered to

Details	
Product Status	Active
Applications	USB Microcontroller
Core Processor	M8C
Program Memory Type	FLASH (8kB)
Controller Series	CY7C643xx
RAM Size	1K x 8
Interface	I²C, SPI, USB
Number of I/O	25
Voltage - Supply	3V ~ 5.5V
Operating Temperature	0°C ~ 70°C
Mounting Type	Surface Mount
Package / Case	32-UFQFN Exposed Pad
Supplier Device Package	32-QFN (5x5)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/cy7c64343-32lqxc

Functional Overview

The enCoRe V family of devices are designed to replace multiple traditional full-speed USB microcontroller system components with one, low cost single-chip programmable component. Communication peripherals (I^2C/SPI), a fast CPU, Flash program memory, SRAM data memory, and configurable I/O are included in a range of convenient pinouts.

The architecture for this device family, as illustrated in the enCoRe V Block Diagram on page 1, consists of two main areas: the CPU core and the system resources. Depending on the enCoRe V package, up to 36 GPIO are also included.

This product is an enhanced version of Cypress's successful full speed-USB peripheral controllers. Enhancements include faster CPU at lower voltage operation, lower current consumption, twice the RAM and Flash, hot-swappable I/Os, I^2C hardware address recognition, new very low current sleep mode, and new package options.

The enCoRe V Core

The enCoRe V Core is a powerful engine that supports a rich instruction set. It encompasses SRAM for data storage, an interrupt controller, sleep and watchdog timers, and IMO and ILO. The CPU core, called the M8C, is a powerful processor with speeds up to 24 MHz. The M8C is a four-MIPS, 8-bit Harvard architecture microprocessor.

During USB operation, the CPU speed can be set to any setting. Be aware that USB throughput decreases with a decrease in CPU speed. For maximum throughput, the CPU clock should be made equal to the system clock. The system clock must be 24 MHz for USB operation.

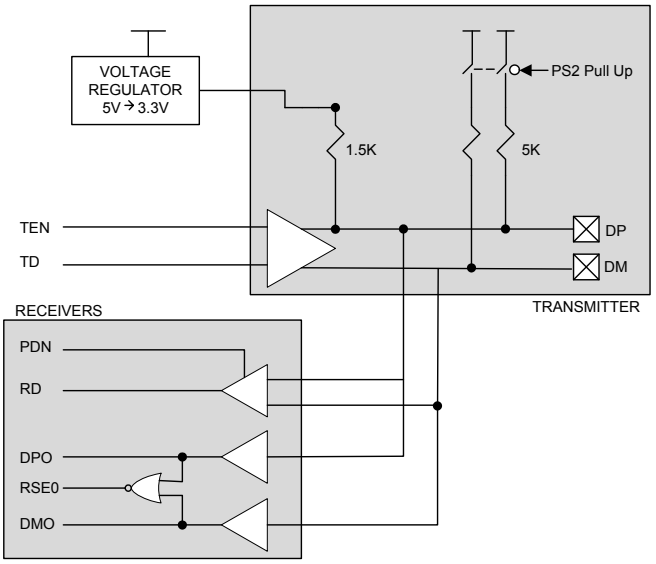
System resources provide additional capability, such as a configurable I^2C slave and SPI master-slave communication interface and various system resets supported by the M8C.

Full-Speed USB

The enCoRe V USB system resource adheres to the USB 2.0 Specification for full speed devices operating at 12 Mb/second with one upstream port and one USB address. enCoRe V USB consists of these components:

- Serial interface engine (SIE) block.
- PSoC memory arbiter (PMA) block.
- 512 bytes of dedicated SRAM.
- A full-speed USB Transceiver with internal regulator and two dedicated USB pins.

Figure 1. USB Transceiver Regulator



At the enCoRe V system level, the full-speed USB system resource interfaces to the rest of the enCoRe V by way of the M8C's register access instructions and to the outside world by way of the two USB pins. The SIE supports nine endpoints including a bidirectional control endpoint (endpoint 0) and eight unidirectional data endpoints (endpoints 1 to 8). The unidirectional data endpoints are individually configurable as either IN or OUT.

Low value series resistors R_{EXT} (22 Ω) must be added externally to the D+ and D– lines to meet the driving impedance requirement for full-speed USB.

The USB Serial Interface Engine (SIE) allows the enCoRe V device to communicate with the USB host at full speed data rates (12 Mb/s). The SIE simplifies the interface to USB traffic by automatically handling the following USB processing tasks without firmware intervention:

- Translates the encoded received data and formats the data to be transmitted on the bus.
- Generates and checks cyclical redundancy checks (CRCs). Incoming packets failing checksum verification are ignored.
- Checks addresses. Ignores all transactions not addressed to the device.
- Sends appropriate ACK/NAK/Stall handshakes.
- Identifies token type (SETUP, IN, OUT) and sets the appropriate token bit once a valid token in received.
- Identifies Start-of-Frame (SOF) and saves the frame count.
- Sends data to or retrieves data from the USB SRAM, by way of the PSoC Memory Arbiter (PMA).

Additional System Resources

System resources, some of which have been previously listed, provide additional capability useful to complete systems. Additional resources include low voltage detection and power on reset. The following statements describe the merits of each system resource.

- Low voltage detection (LVD) interrupts can signal the application of falling voltage levels, while the advanced POR (power on reset) circuit eliminates the need for a system supervisor.
- The 5 V maximum input, 1.8, 2.5, or 3 V selectable output, LDO regulator provides regulation for I/Os. A register controlled bypass mode enables the user to disable the LDO.
- Standard Cypress PSoC IDE tools are available for debugging the enCoRe V family of parts.

Getting Started

The quickest path to understanding the enCoRe V silicon is by reading this data sheet and using the PSoC Designer Integrated Development Environment (IDE). This datasheet is an overview of the PSoC integrated circuit and presents specific pin, register, and electrical specifications. For in-depth information, along with detailed programming information, see the *enCoRe™ V CY7C643xx, enCoRe™ V LV CY7C604xx Technical Reference Manual (TRM)* for this PSoC device.

For up-to-date ordering, packaging, and electrical specification information, see the latest PSoC device data sheets on the web at http://www.cypress.com.

Application Notes

Application notes are an excellent introduction to the wide variety of possible PSoC designs and are available at http://www.cypress.com.

Development Kits

PSoC development kits are available online from Cypress at http://www.cypress.com and through a growing number of regional and global distributors, including Arrow, Avnet, Digi-Key, Farnell, Future Electronics, and Newark.

Training

Free PSoC technical training (on demand, webinars, and workshops) is available online at http://www.cypress.com. The training covers a wide variety of topics and skill levels to assist you in your designs.

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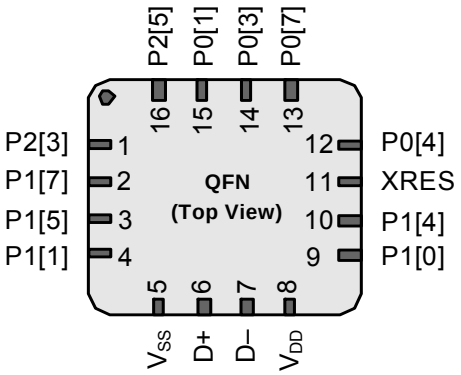
Pin Information

The enCoRe V USB device is available in a variety of packages which are listed and illustrated in the subsequent tables.

16-pin part pinout

Figure 6. CY7C64315/CY7C64316 16-pin enCoRe V USB Device



Pin Definitions

16-pin part pinout (QFN)

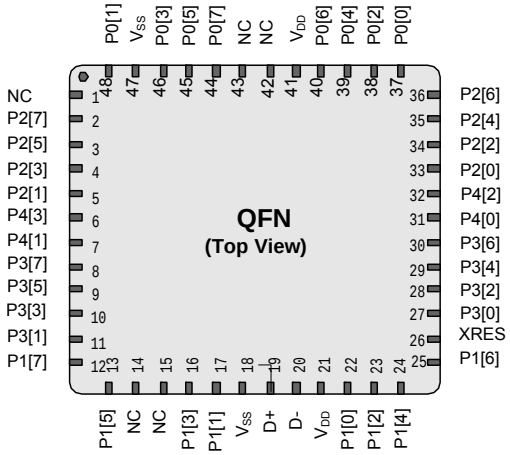
Pin No.	Type	Name	Description
1	I/O	P2[3]	Digital I/O, crystal input (Xin)
2	I/OHR	P1[7]	Digital I/O, SPI SS, I^2C SCL
3	I/OHR	P1[5]	Digital I/O, SPI MISO, I^2C SDA
4	I/OHR	P1[1][1, 2]	Digital I/O, ISSP CLK, I^2C SCL, SPI MOSI
5	Power	V_{SS}	Ground connection
6	USB line	D+	USB PHY
7	USB line	D–	USB PHY
8	Power	V_{DD}	Supply
9	I/OHR	P1[0][1, 2]	Digital I/O, ISSP DATA, I^2C SDA, SPI CLK
10	I/OHR	P1[4]	Digital I/O, optional external clock input (EXTCLK)
11	Input	XRES	Active high external reset with internal pull-down
12	I/OH	P0[4]	Digital I/O
13	I/OH	P0[7]	Digital I/O
14	I/OH	P0[3]	Digital I/O
15	I/OH	P0[1]	Digital I/O
16	I/O	P2[5]	Digital I/O, crystal output (Xout)

LEGEND I = Input, O = Output, OH = 5 mA High Output Drive, R = Regulated Output

Notes
1. During power up or reset event, device P1[0] and P1[1] may disturb the I^2C bus. Use alternate pins if issues are encountered.
2. These are the in-system serial programming (ISSP) pins that are not High Z at power on reset (POR).

48-pin Part Pinout

Figure 8. CY7C64355/CY7C64356 48-pin enCoRe V USB Device



Pin Definitions

48-pin Part Pinout (QFN)

Pin No.	Type	Pin Name	Description
1	NC	NC	No connection
2	I/O	P2[7]	Digital I/O
3	I/O	P2[5]	Digital I/O, crystal out (Xout)
4	I/O	P2[3]	Digital I/O, crystal in (Xin)
5	I/O	P2[1]	Digital I/O
6	I/O	P4[3]	Digital I/O
7	I/O	P4[1]	Digital I/O
8	I/O	P3[7]	Digital I/O
9	I/O	P3[5]	Digital I/O
10	I/O	P3[3]	Digital I/O
11	I/O	P3[1]	Digital I/O
12	I/OHR	P1[7]	Digital I/O, I^2C SCL, SPI SS
13	I/OHR	P1[5]	Digital I/O, I^2C SDA, SPI MISO
14	NC	NC	No connection
15	NC	NC	No connection
16	I/OHR	P1[3]	Digital I/O, SPI CLK
17	I/OHR	P1[1][5, 6]	Digital I/O, ISSP CLK, I^2C SCL, SPI MOSI
18	Power	V_{SS}	Supply ground
19	I/O	D+	USB
20	I/O	D–	USB
21	Power	V_{DD}	Supply voltage
22	I/OHR	P1[0][5, 6]	Digital I/O, ISSP DATA, I^2C SDA, SPI CLK
23	I/OHR	P1[2]	Digital I/O

Notes
5. During power up or reset event, device P1[0] and P1[1] may disturb the I^2C bus. Use alternate pins if issues are encountered.
6. These are the in-system serial programming (ISSP) pins that are not High Z at power on reset (POR).

Register Reference

The section discusses the registers of the enCoRe V device. It lists all the registers in mapping tables, in address order.

Register Conventions

The register conventions specific to this section are listed in the following table.

Table 1. Register Conventions

Convention	Description
R	Read register or bits
W	Write register or bits
L	Logical register or bits
C	Clearable register or bits
#	Access is bit specific

Register Mapping Tables

The enCoRe V device has a total register address space of 512 bytes. The register space is also referred to as I/O space and is broken into two parts: Bank 0 (user space) and Bank 1 (configuration space). The XIO bit in the Flag register (CPU_F) determines which bank the user is currently in. When the XIO bit is set, the user is said to be in the “extended” address space or the “configuration” registers.

Table 2. Register Map Bank 0 Table: User Space

Name	Addr (0, Hex)	Access	Name	Addr (0, Hex)	Access	Name	Addr (0, Hex)	Access	Name	Addr (0, Hex)	Access
PRT0DR	00	RW	EP1_CNT0	40	#		80			C0	
PRT0IE	01	RW	EP1_CNT1	41	RW		81			C1	
	02		EP2_CNT0	42	#		82			C2	
	03		EP2_CNT1	43	RW		83			C3	
PRT1DR	04	RW	EP3_CNT0	44	#		84			C4	
PRT1IE	05	RW	EP3_CNT1	45	RW		85			C5	
	06		EP4_CNT0	46	#		86			C6	
	07		EP4_CNT1	47	RW		87			C7	
PRT2DR	08	RW	EP5_CNT0	48	#		88		I2C_XCFG	C8	RW
PRT2IE	09	RW	EP5_CNT1	49	RW		89		I2C_XSTAT	C9	R
	0A		EP6_CNT0	4A	#		8A		I2C_ADDR	CA	RW
	0B		EP6_CNT1	4B	RW		8B		I2C_BP	CB	R
PRT3DR	0C	RW	EP7_CNT0	4C	#		8C		I2C_CP	CC	R
PRT3IE	0D	RW	EP7_CNT1	4D	RW		8D		CPU_BP	CD	RW
	0E		EP8_CNT0	4E	#		8E		CPU_CP	CE	R
	0F		EP8_CNT1	4F	RW		8F		I2C_BUF	CF	RW
PRT4DR	10	RW		50			90		CUR_PP	D0	RW
PRT4IE	11	RW		51			91		STK_PP	D1	RW
	12			52			92			D2	
	13			53			93		IDX_PP	D3	RW
	14			54			94		MVR_PP	D4	RW
	15			55			95		MVW_PP	D5	RW
	16			56			96		I2C_CFG	D6	RW
	17			57			97		I2C_SCR	D7	#
	18		PMA0_DR	58	RW		98		I2C_DR	D8	RW
	19		PMA1_DR	59	RW		99			D9	
	1A		PMA2_DR	5A	RW		9A		INT_CLR0	DA	RW
	1B		PMA3_DR	5B	RW		9B		INT_CLR1	DB	RW
	1C		PMA4_DR	5C	RW		9C		INT_CLR2	DC	RW
	1D		PMA5_DR	5D	RW		9D			DD	
	1E		PMA6_DR	5E	RW		9E		INT_MSK2	DE	RW
	1F		PMA7_DR	5F	RW		9F		INT_MSK1	DF	RW
	20			60			A0		INT_MSK0	E0	RW
	21			61			A1		INT_SW_EN	E1	RW
	22			62			A2		INT_VC	E2	RC
	23			63			A3		RES_WDT	E3	W
	24		PMA8_DR	64	RW		A4			E4	
	25		PMA9_DR	65	RW		A5			E5	
	26		PMA10_DR	66	RW		A6			E6	
	27		PMA11_DR	67	RW		A7			E7	
	28		PMA12_DR	68	RW		A8			E8	
SPI_TXR	29	W	PMA13_DR	69	RW		A9			E9	
SPI_RXR	2A	R	PMA14_DR	6A	RW		AA			EA	
SPI_CR	2B	#	PMA15_DR	6B	RW		AB			EB	
	2C		TMP_DR0	6C	RW		AC			EC	
	2D		TMP_DR1	6D	RW		AD			ED	
	2E		TMP_DR2	6E	RW		AE			EE	
	2F		TMP_DR3	6F	RW		AF			EF	
	30			70		PT0_CFG	B0	RW		F0	
USB_SOF0	31	R		71		PT0_DATA1	B1	RW		F1	
USB_SOF1	32	R		72		PT0_DATA0	B2	RW		F2	
USB_CR0	33	RW		73		PT1_CFG	B3	RW		F3	
USBIO_CR0	34	#		74		PT1_DATA1	B4	RW		F4	
USBIO_CR1	35	#		75		PT1_DATA0	B5	RW		F5	
EP0_CR	36	#		76		PT2_CFG	B6	RW		F6	
EP0_CNT0	37	#		77		PT2_DATA1	B7	RW	CPU_F	F7	RL
EP0_DR0	38	RW		78		PT2_DATA0	B8	RW		F8	
EP0_DR1	39	RW		79			B9			F9	
EP0_DR2	3A	RW		7A			BA			FA	
EP0_DR3	3B	RW		7B			BB			FB	
EP0_DR4	3C	RW		7C			BC			FC	
EP0_DR5	3D	RW		7D			BD			FD	
EP0_DR6	3E	RW		7E			BE		CPU_SCR1	FE	#
EP0_DR7	3F	RW		7F			BF		CPU_SCR0	FF	#

Gray fields are reserved; do not access these fields. # Access is bit specific.

DC Electrical Characteristics

DC Chip Level Specifications

Table 6 lists guaranteed maximum and minimum specifications for the entire voltage and temperature ranges.

Table 6. DC Chip Level Specifications

Symbol	Description	Conditions	Min	Typ	Max	Units
V_{DD}	Operating voltage [7, 9]	No USB activity.	3.0	–	5.5	V
$I_{DD24,3}$	Supply current, CPU = 24 MHz	Conditions are V_{DD} = 3.0 V, T_A = 25 °C, CPU = 24 MHz, No USB/I^2C/SPI.	–	2.9	4.0	mA
$I_{DD12,3}$	Supply current, CPU = 12 MHz	Conditions are V_{DD} = 3.0 V, T_A = 25 °C, CPU = 12 MHz, No USB/I^2C/SPI.	–	1.7	2.6	mA
$I_{DD6,3}$	Supply current, CPU = 6 MHz	Conditions are V_{DD} = 3.0 V, T_A = 25 °C, CPU = 6 MHz, No USB/I^2C/SPI.	–	1.2	1.8	mA
$I_{SB1,3}$	Standby current with POR, LVD, and sleep timer	V_{DD} = 3.0 V, T_A = 25 °C, I/O regulator turned off.	–	1.1	1.5	µA
$I_{SB0,3}$	Deep sleep current	V_{DD} = 3.0 V, T_A = 25 °C, I/O regulator turned off.	–	0.1	–	µA
V_{DDUSB}	Operating voltage	USB activity, USB regulator enabled	4.35	–	5.25	V
$I_{DD24,5}$	Supply current, CPU = 24 MHz	Conditions are V_{DD} = 5.0 V, T_A = 25 °C, CPU = 24 MHz, IMO = 24 MHz USB Active, No I^2C/SPI.	–	7.1	–	mA
$I_{DD12,5}$	Supply current, CPU = 12 MHz	Conditions are V_{DD} = 5.0 V, T_A = 25 °C, CPU = 12 MHz, IMO = 24 MHz USB Active, No I^2C/SPI.	–	6.2	–	mA
$I_{DD6,5}$	Supply current, CPU = 6 MHz	Conditions are V_{DD} = 5.0 V, T_A = 25 °C, CPU = 6 MHz, IMO = 24 MHz USB Active, No I^2C/SPI	–	5.8	–	mA
$I_{SB1,5}$	Standby current with POR, LVD, and sleep timer	V_{DD} = 5.0 V, T_A = 25 °C, I/O regulator turned off.	–	1.1	–	µA
$I_{SB0,5}$	Deep sleep current	V_{DD} = 5.0 V, T_A = 25 °C, I/O regulator turned off.	–	0.1	–	µA
V_{DDUSB}	Operating voltage	USB activity, USB regulator bypassed	3.15	3.3	3.60	V

Notes
10. Higher storage temperatures reduce data retention time. Recommended storage temperature is +25 °C ± 25 °C. Extended duration storage temperatures above 85 °C degrade reliability.
11. The temperature rise from ambient to junction is package specific. See Package Handling on page 31. The user must limit the power consumption to comply with this requirement.

Table 7. DC Characteristics – USB Interface

Symbol	Description	Conditions	Min	Typ	Max	Units
Rusbi	USB D+ pull-up resistance	With idle bus	0.900	–	1.575	kΩ
Rusba	USB D+ pull-up resistance	While receiving traffic	1.425	–	3.090	kΩ
Vohusb	Static output high		2.8	–	3.6	V
Volusb	Static output low		–	–	0.3	V
Vdi	Differential input sensitivity		0.2	–	–	V
Vcm	Differential input common mode range		0.8	–	2.5	V
Vse	Single-ended receiver threshold		0.8	–	2.0	V
Cin	Transceiver capacitance			–	50	pF
Iio	High Z state data Line Leakage	On D+ or D– line	–10	–	+10	µA
Rps2	PS/2 Pull Up Resistance		3	5	7	kΩ
Rext	External USB Series Resistor	In series with each USB pin	21.78	22.0	22.22	Ω

ADC Electrical Specifications

Table 8. ADC User Module Electrical Specifications

Symbol	Description	Conditions	Min	Typ	Max	Units
Input						
V_{IN}	Input voltage range		0	–	VREFADC	V
C_{IIN}	Input capacitance		–	–	5	pF
R_{IN}	Input resistance	Equivalent switched cap input resistance for 8-, 9-, or 10-bit resolution	1/(500fF* Data Clock)	1/(400fF* Data Clock)	1/(300fF* Data Clock)	Ω
Reference						
V_{REFADC}	ADC reference voltage		1.14	–	1.26	V
Conversion Rate						
F_{CLK}	Data clock	Source is chip's internal main oscillator. See AC Chip-Level Specifications for accuracy	2.25	–	6	MHz
S8	8-bit sample rate	Data Clock set to 6 MHz. Sample Rate = 0.001/ (2^Resolution/Data Clock)	–	23.4375	–	ksps
S10	10-bit sample rate	Data Clock set to 6 MHz. Sample Rate = 0.001/ (2^Resolution/Data Clock)	–	5.859	–	ksps
DC Accuracy						
RES	Resolution	Can be set to 8-, 9-, or 10-bit	8	–	10	bits
DNL	Differential nonlinearity		–1	–	+2	LSB
INL	Integral nonlinearity		–2	–	+2	LSB
E_{Offset}	Offset error	8-bit resolution	0	3.2	19.2	LSB
		10-bit resolution	0	12.8	76.8	LSB
E_{gain}	Gain error	For any resolution	–5	–	+5	%FSR
Power						
I_{ADC}	Operating current		–	2.1	2.6	mA
PSRR	Power supply rejection ratio	PSRR (V_{DD} > 3.0 V)	–	24	–	dB
		PSRR (V_{DD} < 3.0 V)	–	30	–	dB

DC General Purpose I/O Specifications

Table 9 lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 3.0 V to 5.5 V and package specific temperature range. Typical parameters apply to 5 V and 3.3 V at 25 °C. These are for design guidance only.

Table 9. 3.0 V and 5.5 V DC GPIO Specifications

Symbol	Description	Conditions	Min	Typ	Max	Units
R_{PU}	Pull-up resistor		4	5.6	8	kΩ
V_{OH1}	High output voltage Port 2 or 3 pins	$I_{OH} \leq 10$ µA, maximum of 10 mA source current in all I/Os.	$V_{DD} - 0.2$	–	–	V
V_{OH2}	High output voltage Port 2 or 3 Pins	I_{OH} = 1 mA, maximum of 20 mA source current in all I/Os.	$V_{DD} - 0.9$	–	–	V
V_{OH3}	High output voltage Port 0 or 1 pins with LDO regulator disabled	$I_{OH} < 10$ µA, maximum of 10 mA source current in all I/Os.	$V_{DD} - 0.2$	–	–	V
V_{OH4}	High output voltage Port 0 or 1 pins with LDO regulator disabled	I_{OH} = 5 mA, maximum of 20 mA source current in all I/Os.	$V_{DD} - 0.9$	–	–	V
V_{OH5}	High output voltage Port 1 pins with LDO regulator enabled for 3 V Out	$I_{OH} < 10$ µA, $V_{DD} > 3.1$ V, maximum of 4 I/Os all sourcing 5 mA	2.85	3.00	3.3	V
V_{OH6}	High output voltage Port 1 pins with LDO regulator enabled for 3 V out	I_{OH} = 5 mA, $V_{DD} > 3.1$ V, maximum of 20 mA source current in all I/Os	2.20	–	–	V
V_{OH7}	High output voltage Port 1 pins with LDO enabled for 2.5 V out	$I_{OH} < 10$ µA, $V_{DD} > 3.0$ V, maximum of 20 mA source current in all I/Os	2.35	2.50	2.75	V
V_{OH8}	High output voltage Port 1 pins with LDO enabled for 2.5 V out	I_{OH} = 2 mA, $V_{DD} > 3.0$ V, maximum of 20 mA source current in all I/Os	1.90	–	–	V
V_{OH9}	High output voltage Port 1 pins with LDO enabled for 1.8 V out	$I_{OH} < 10$ µA, $V_{DD} > 3.0$ V, maximum of 20 mA source current in all I/Os	1.60	1.80	2.1	V
V_{OH10}	High output voltage Port 1 pins with LDO enabled for 1.8 V out	I_{OH} = 1 mA, $V_{DD} > 3.0$ V, maximum of 20 mA source current in all I/Os	1.20	–	–	V
V_{OL}	Low output voltage	I_{OL} = 25 mA, $V_{DD} > 3.3$ V, maximum of 60 mA sink current on even port pins (for example, P0[2] and P1[4]) and 60 mA sink current on odd port pins (for example, P0[3] and P1[5]).	–	–	0.75	V
V_{IL}	Input low voltage		–	–	0.8	V
V_{IH}	Input high voltage		2.0	–	–	V
V_H	Input hysteresis voltage		–	80	–	mV
I_{IL}	Input leakage (absolute value)		–	0.001	1	µA
C_{PIN}	Pin capacitance	Package and pin dependent. Temp = 25 °C.	0.5	1.7	5	pF

DC POR and LVD Specifications

Table 10 lists guaranteed maximum and minimum specifications for the entire voltage and temperature ranges.

Table 10. DC POR and LVD Specifications

Symbol	Description	Conditions	Min	Typ	Max	Units
V_{PPOR}	V_{DD} value for PPOR trip[12] PORLEV[1:0] = 10b		–	2.82	2.95	V
	V_{DD} value for LVD trip					
V_{LVD0}	VM[2:0] = 000b		–	–	–	V
V_{LVD1}	VM[2:0] = 001b		–	–	–	V
V_{LVD2}	VM[2:0] = 010b		2.85	2.92	2.99	V
V_{LVD3}	VM[2:0] = 011b		2.95	3.02	3.09	V
V_{LVD4}	VM[2:0] = 100b		3.06	3.13	3.20	V
V_{LVD5}	VM[2:0] = 101b		–-	–	–	V
V_{LVD6}	VM[2:0] = 110b		–	–	–	V
V_{LVD7}	VM[2:0] = 111b		4.62	4.73	4.83	V

DC Programming Specifications

Table 11 lists guaranteed maximum and minimum specifications for the entire voltage and temperature ranges.

Table 11. DC Programming Specifications

Symbol	Description	Conditions	Min	Typ	Max	Units
$V_{DDIWRITE}$	Supply voltage for flash write operations		1.71	–	5.25	V
I_{DDP}	Supply current during programming or verify		–	5	25	mA
V_{ILP}	Input low voltage during programming or verify	See appropriate DC General Purpose I/O Specifications table	–	–	V_{IL}	V
V_{IHP}	Input high voltage during programming or verify		1.71	–	$V_{DDIWRITE}$ + 0.3	V
I_{ILP}	Input current when applying Vilp to P1[0] or P1[1] during programming or verify[13]		–	–	0.2	mA
I_{IHP}	Input current when applying Vihp to P1[0] or P1[1] during programming or verify[13]		–	–	1.5	mA
V_{OLP}	Output low voltage during programming or verify		–	–	V_{SS} + 0.75	V
V_{OHP}	Output high voltage during programming or verify		$V_{DDIWRITE}$ – 0.9	–	$V_{DDIWRITE}$	V
$Flash_{ENPB}$	Flash write endurance[14]		50,000	–	–	Cycles
$Flash_{DR}$	Flash data retention[15]		10	20	–	Years

Notes
12. Always greater than 50 mV above V_{PPOR} (PORLEV = 10) for falling supply.
13. Driving internal pull down resistor.
14. Erase/write cycles per block.
15. Following maximum Flash write cycles at Tamb = 55 °C and Tj = 70 °C.

AC Electrical Characteristics

AC Chip Level Specifications

The following tables list guaranteed maximum and minimum specifications for the entire voltage and temperature ranges.

Table 12. AC Chip Level Specifications

Symbol	Description	Conditions	Min	Typ	Max	Units
F_{CPU}	Processing frequency[16]		5.7	–	25.2	MHz
F_{32K1}	Internal low-speed oscillator (ILO) frequency	Trimmed[17]	19	32	50	kHz
F_{32K_U}	ILO untrimmed frequency)		13	32	82	kHz
F_{32K2}	ILO frequency	Untrimmed	13	32	82	kHz
F_{IMO24}	Internal main oscillator (IMO) stability for 24 MHz ± 5%(12)		22.8	24	25.2	MHz
F_{IMO12}	IMO stability for 12 MHz[17]		11.4	12	12.6	MHz
F_{IMO6}	IMO stability for 6 MHz[17]		5.7	6.0	6.3	MHz
DC_{IMO}	Duty cycle of IMO		40	50	60	%
DC_{ILO}	ILO duty cycle		40	50	60	%
SR_{POWER_UP}	Power supply slew rate		–	–	250	V/ms
T_{XRST}	External reset pulse width at power-up	After supply voltage is valid	1	–	–	ms
T_{XRST2}	External reset pulse width after power-up[18]	Applies after part has booted	10	–	–	µs

Table 13. AC Characteristics – USB Data Timings

Symbol	Description	Conditions	Min	Typ	Max	Units
Tdrate	Full speed data rate	Average bit rate	11.97	12	12.03	MHz
Tdjr1	Receiver data jitter tolerance	To next transition	–18.5	–	18.5	ns
Tdjr2	Receiver data jitter tolerance	To pair transition	–9	–	9	ns
Tudj1	Driver differential jitter	To next transition	–3.5	–	3.5	ns
Tudj2	Driver differential jitter	To pair transition	–4.0	–	4.0	ns
Tfdeop	Source jitter for differential transition	To SE0 transition	–2	–	5	ns
Tfeopt	Source SE0 interval of EOP		160	–	175	ns
Tfeopr	Receiver SE0 interval of EOP		82	–	–	ns
Tfst	Width of SE0 interval during differential transition		–	–	14	ns

Table 14. AC Characteristics – USB Driver

Symbol	Description	Conditions	Min	Typ	Max	Units
Tr	Transition rise time	50 pF	4	–	20	ns
Tf	Transition fall time	50 pF	4	–	20	ns
TR [19]	Rise/fall time matching		90.00	–	111.1	%
Vcrs	Output signal crossover voltage		1.3	–	2.0	V

Notes

16. V_{DD} = 3.0 V and T_J = 85 °C, CPU speed.
17. Trimmed for 3.3 V operation using factory trim values.
18. The minimum required XRES pulse length is longer when programming the device (see Table 17 on page 24).
19. Errata: Rising to falling rate matching of the USB D+ and D- lines has a corner case issue when operating voltage is below 3.3 V. Refer to "Errata" on page 35 for more details.

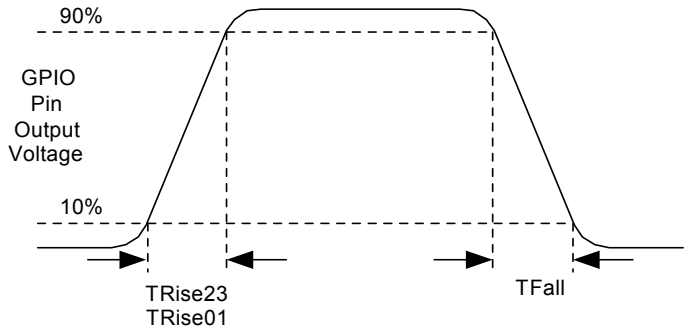
AC General Purpose I/O Specifications

Table 15 lists guaranteed maximum and minimum specifications for the entire voltage and temperature ranges.

Table 15. AC GPIO Specifications

Symbol	Description	Conditions	Min	Typ	Max	Units
F_{GPIO}	GPIO operating frequency	Normal strong mode, Ports 0, 1	–	–	12	MHz
TRise23	Rise time, strong mode Ports 2, 3	V_{DD} = 3.0 to 3.6 V, 10% - 90%	15	–	80	ns
TRise01	Rise time, strong mode Ports 0, 1	V_{DD} = 3.0 to 3.6 V, 10% - 90%	10	–	50	ns
TFall	Fall time, strong mode All Ports	V_{DD} = 3.0 to 3.6 V, 10% - 90%	10	–	50	ns

Figure 11. GPIO Timing Diagram



AC External Clock Specifications

Table 16 lists guaranteed maximum and minimum specifications for the entire voltage and temperature ranges.

Table 16. AC External Clock Specifications

Symbol	Description	Conditions	Min	Typ	Max	Units
F_{OSCEXT}	Frequency		0.750	–	25.2	MHz
–	High period		20.6	–	5300	ns
–	Low period		20.6	–	–	ns
–	Power-up IMO to switch		150	–	–	µs

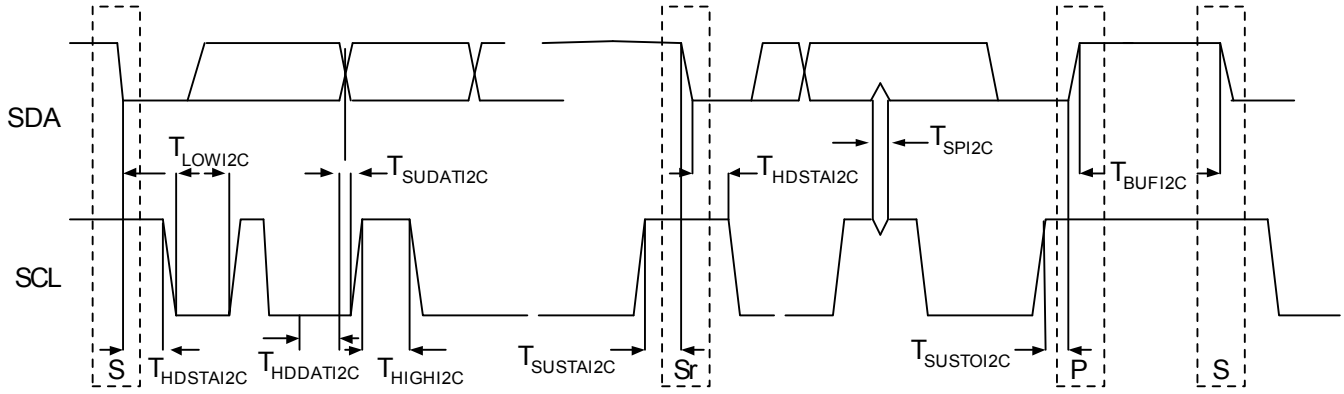
AC I²C Specifications

Table 18 lists guaranteed maximum and minimum specifications for the entire voltage and temperature ranges.

Table 18. AC Characteristics of the I²C SDA and SCL Pins

Symbol	Description	Standard Mode		Fast Mode		Units
		Min	Max	Min	Max	
F_{SCLI2C}	SCL clock frequency	0	100	0	400	kHz
$T_{HDSTAI2C}$	Hold time (repeated) START condition. After this period, the first clock pulse is generated	4.0	–	0.6	–	µs
T_{LOWI2C}	LOW period of the SCL clock	4.7	–	1.3	–	µs
$T_{HIGHI2C}$	HIGH period of the SCL clock	4.0	–	0.6	–	µs
$T_{SUSTAI2C}$	Setup time for a repeated START condition	4.7	–	0.6	–	µs
$T_{HDDATI2C}$	Data hold time	0	–	0	–	µs
$T_{SUDATI2C}$	Data setup time	250	–	100[20]	–	ns
$T_{SUSTOI2C}$	Setup time for STOP condition	4.0	–	0.6	–	µs
T_{BUFI2C}	Bus free time between a STOP and START condition	4.7	–	1.3	–	µs
T_{SPI2C}	Pulse width of spikes are suppressed by the input filter	–	–	0	50	ns

Figure 13. Definition of Timing for Fast/Standard Mode on the I²C Bus



Note

20. A Fast mode I²C bus device can be used in a standard mode I²C bus system, but the requirement $t_{SUDAT} \geq 250$ ns must then be met. This is automatically the case if the device does not stretch the LOW period of the SCL signal. If such device does stretch the LOW period of the SCL signal, it must output the next data bit to the SDA line $t_{rmax} + t_{SUDAT} = 1000 + 250 = 1250$ ns (according to the standard mode I²C bus specification) before the SCL line is released.

Table 19. SPI Master AC Specifications

Symbol	Description	Conditions	Min	Typ	Max	Units
F_{SCLK}	SCLK clock frequency		–	–	6	MHz
DC	SCLK duty cycle		–	50	–	%
T_{SETUP}	MISO to SCLK setup time		60	–	–	ns
T_{HOLD}	SCLK to MISO hold time		40	–	–	ns
T_{OUT_VAL}	SCLK to MOSI valid time		–	–	40	ns
T_{OUT_H}	SCLK to MOSI hold time		40	–	–	ns

Figure 14. SPI Master Mode 0 and 2

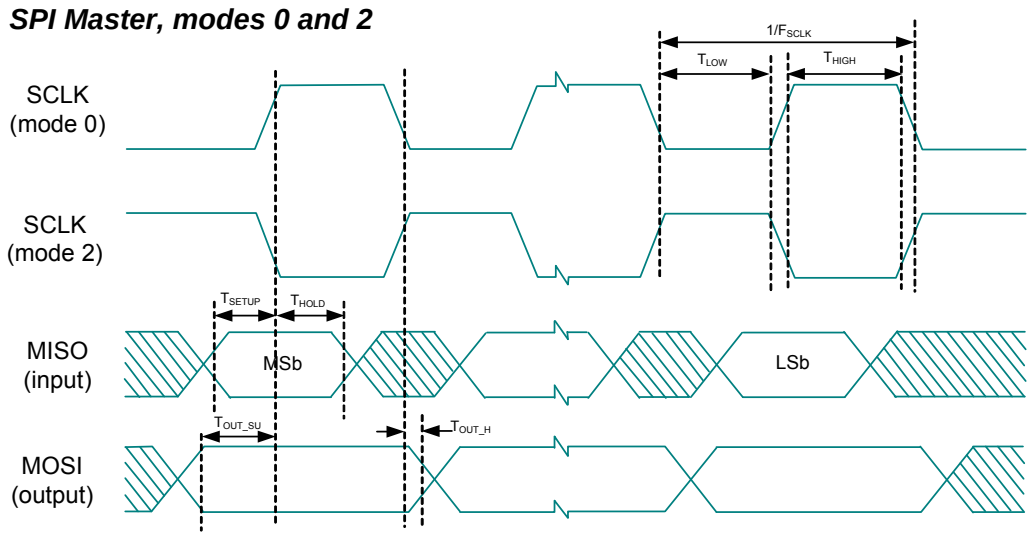


Figure 15. SPI Master Mode 1 and 3

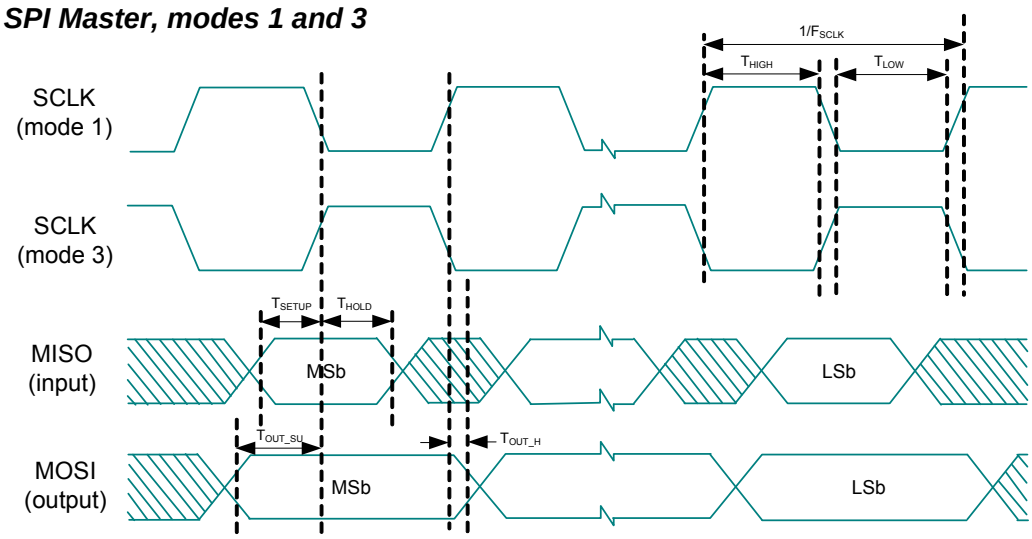


Table 20. SPI Slave AC Specifications

Symbol	Description	Conditions	Min	Typ	Max	Units
F_{SCLK}	SCLK clock frequency		0.0469	–	12	MHz
T_{LOW}	SCLK low time		41.67	–	–	ns
T_{HIGH}	SCLK high time		41.67	–	–	ns
T_{SETUP}	MOSI to SCLK setup time		30	–	–	ns
T_{HOLD}	SCLK to MOSI hold time		50	–	–	ns
T_{SS_MISO}	SS low to MISO valid		–	–	153	ns
T_{SCLK_MISO}	SCLK to MISO valid		–	–	125	ns
T_{SS_HIGH}	SS high time		50	–	–	ns
T_{SS_CLK}	Time from SS low to first SCLK		$2/F_{SCLK}$	–	–	ns
T_{CLK_SS}	Time from last SCLK to SS high		$2/F_{SCLK}$	–	–	ns

Figure 16. SPI Slave Mode 0 and 2

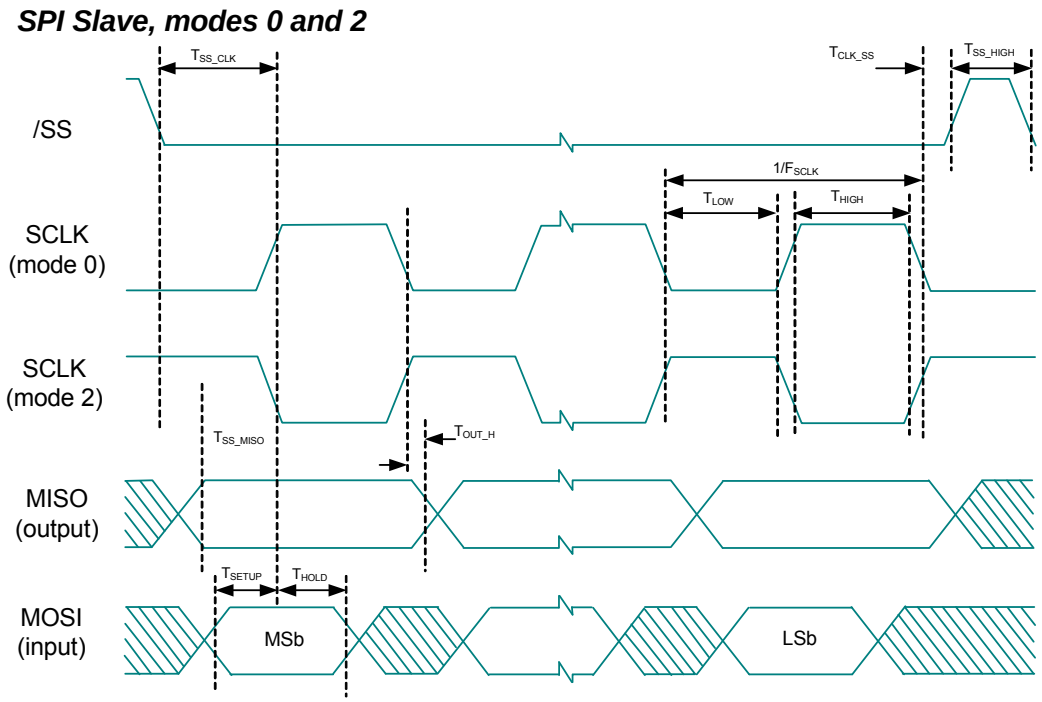


Figure 17. SPI Slave Mode 1 and 3

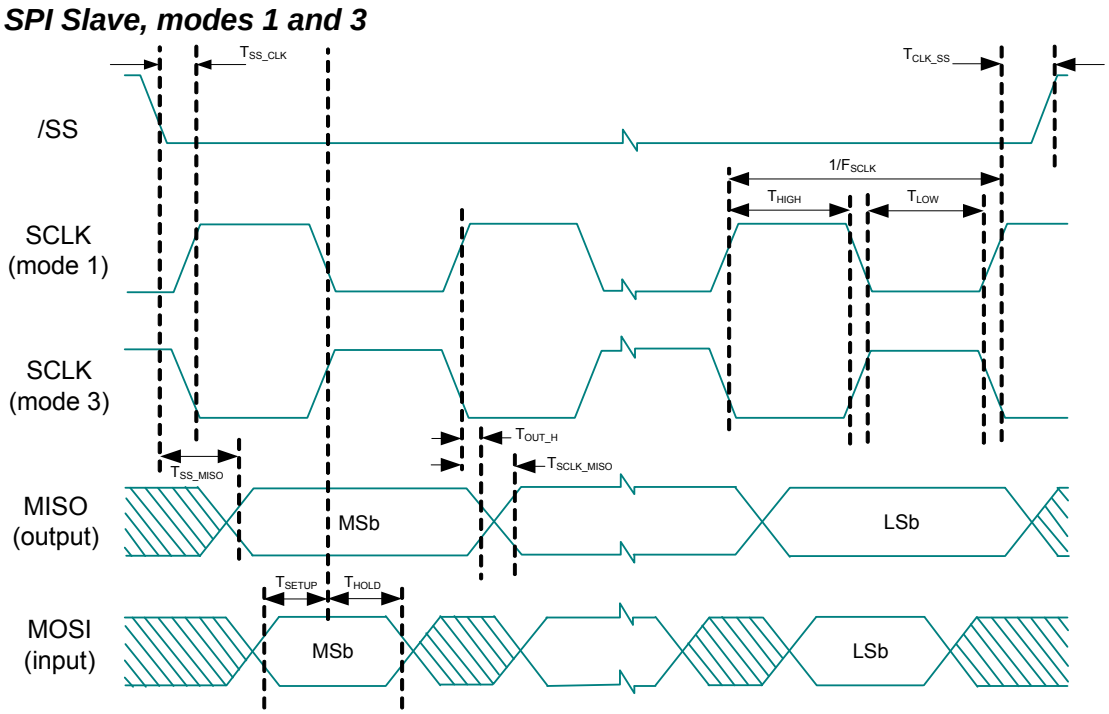
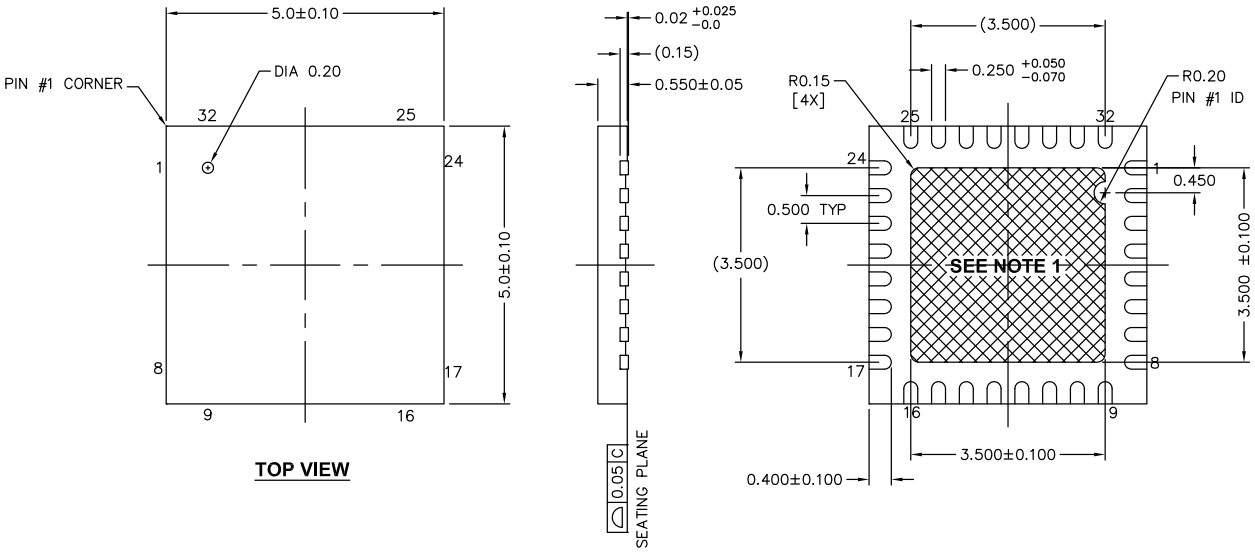


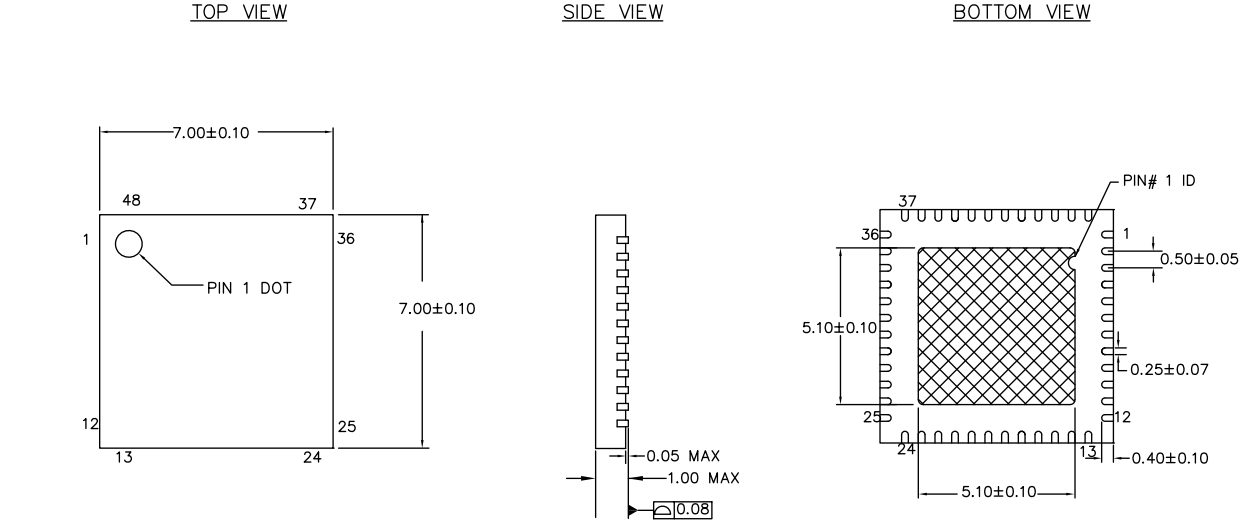
Figure 19. 32-pin QFN (5 × 5 × 0.55 mm) LQ32 3.5 × 3.5 E-Pad (Sawn) Package Outline, 001-42168



NOTES:
1. HATCH AREA IS SOLDERABLE EXPOSED PAD
2. BASED ON REF JEDEC # MO−248
3. PACKAGE WEIGHT: 0.0388g
4. DIMENSIONS ARE IN MILLIMETERS

001-42168 *E

Figure 20. 48-pin QFN (7 × 7 × 1.00 mm) LT48A 5.1 × 5.1 E-Pad (Sawn) Package Outline, 001-13191



NOTES:
1. HATCH AREA IS SOLDERABLE EXPOSED METAL.
2. REFERENCE JEDEC#: MO−220
3. PACKAGE WEIGHT: 13 ± 1 mg
4. ALL DIMENSIONS ARE IN MILLIMETERS

001-13191 *H

Package Handling

Some IC packages require baking before they are soldered onto a PCB to remove moisture that may have been absorbed after leaving the factory. A label on the package has details about the actual bake temperature and the minimum bake time to remove this moisture. The maximum bake time is the aggregate time that the parts exposed to the bake temperature. Exceeding this exposure may degrade device reliability.

Table 21. Package Handling

Parameter	Description	Minimum	Typical	Maximum	Unit
TBAKETEMP	Bake temperature	–	125	See package label	°C
TBAKETIME	Bake time	See package label	–	72	hours

Thermal Impedances

Table 22. Thermal Impedances per Package

Package	Typical θ_{JA} [21]
16-pin QFN	32.69 °C / W
32-pin QFN [22]	19.51 °C / W
48-pin QFN [22]	17.68 °C / W

Capacitance on Crystal Pins

Table 23. Typical Package Capacitance on Crystal Pins

Package	Package Capacitance
32-pin QFN	3.2 pF
48-pin QFN	3.3 pF

Solder Reflow Peak Temperature

Following is the minimum solder reflow peak temperature to achieve good solderability.

Table 24. Solder Reflow Peak Temperature

Package	Minimum Peak Temperature [23]	Maximum Peak Temperature
16-pin QFN	240 °C	260 °C
32-pin QFN	240 °C	260 °C
48-pin QFN	240 °C	260 °C

Notes
21. $T_J = T_A$ + Power x θ_{JA}.
22. To achieve the thermal impedance specified for the package, solder the center thermal pad to the PCB ground plane.
23. Higher temperatures may be required based on the solder melting point. Typical temperatures for solder are 220 ± 5 °C with Sn-Pb or 245 ± 5 °C with Sn-Ag-Cu paste. Refer to the solder manufacturer specifications.

Document History Page *(continued)*

Document Title: CY7C6431x/CY7C6434x/CY7C6435x, enCoRe™ V Full Speed USB Controller Document Number: 001-12394				
Rev.	**ECN No.**	**Orig. of Change**	**Submission Date**	**Description of Change**
*F	2583853	TYJ / PYRS / HMT	10/10/08	Converted from Preliminary to Final Added operating voltage ranges with USB ADC resolution changed from 10-bit to 8-bit Rephrased battery monitoring clause in page 1 to include “with external components” Included ADC specifications table Included Voh7, Voh8, Voh9, Voh10 specs Flash data retention – condition added to Note [11] Input leakage spec changed to 25 nA max Under AC Char, Frequency accuracy of ILO corrected GPIO rise time for ports 0,1 and ports 2,3 made common AC Programming specifications updated Included AC Programming cycle timing diagram AC SPI specification updated Spec change for 32-QFN package Input Leakage Current maximum value changed to 1 μA Updated V_{OHV} parameter in Table 13 Updated thermal impedances for the packages Update Development Tools, add Designing with PSoC Designer. Edit, fix links and table format. Update TMs.
*G	2653717	DVJA / PYRS	02/04/09	Updated Features, Functional Overview, Development Tools, and Designing with PSoC Designer sections with edits. Removed ‘GUI - graphical user interface’ from Document Conventions acronym table. Removed ‘O - Only a read/write register or bits’ in Table 4 Edited Table 8: removed 10-bit resolution information and corrected units column. Added package handling section Added 8K part ‘CY7C64343-32LQXC’ to Ordering Information.
*H	2714694	DVJA / AESA	06/04/2009	Updated Block Diagram. Added Full Speed USB, 10-bit ADC, SPI, and I2C Slave sections. ADC Resolution changed from 8-bit to 10-bit Updated Table 9 DC Chip Level Specs Updated Table10 DC Char - USB Interface Updated Table 12 DC POR and LDV Specs Changed operating temperature from Commercial to Industrial Changed Temperature Range to Industrial: –40 to 85°C Figure 9: Changed minimum CPU Frequency from 750 kHz to 5.7 MHz Table 14: Removed “Maximum” from the F_{CPU} description Ordering Information: Replaced ‘C’ with ‘I’ in all part numbers to denote Industrial Temp Range
*I	2764460	DVJA / AESA	09/16/2009	Changed Table 12: ADC Specs Added F_{32K2} (Untrimmed) spec to Table 16: AC Chip level Specs Changed T_{RAMP} spec to SR_{POWER_UP} in Table 16: AC Chip Level Specs Added Table 27: Typical Package Capacitance on Crystal Pins
*J	2811903	DVJA	11/20/2009	Added USB-IF TID number in Features on page 1. Added Note 5 on page 18. Changed V_{IHP} in Table 12 on page 22.

Document History Page *(continued)*

Document Title: CY7C6431x/CY7C6434x/CY7C6435x, enCoRe™ V Full Speed USB Controller Document Number: 001-12394				
Rev.	**ECN No.**	**Orig. of Change**	**Submission Date**	**Description of Change**
*S	4578605	GINS	12/11/2014	Updated Pin Information: Updated 32-pin part pinout: Updated Figure 7 (No change in figure, included CY7C64346 in figure caption). Updated Package Diagrams: spec 001-09116 – Changed revision from *I to *J. Updated Ordering Information: Updated Table 25: Updated part numbers.
*T	5548557	ANKC	12/12/2016	Updated Cypress Logo, Sales Page and Disclaimer. Updated Figure 20 (spec 001-13191 *G to *H) in Package Diagrams. Removed the following obsolete part numbers (Table 26) in Ordering Information: CY7C64343-32LQXI, CY7C64343-32LQXIT, CY7C64345-32LQXI, CY7C64345-32LQXIT, CY7C64356-48LTXI, CY7C64356-48LTXIT.